TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

TPCP8604

High-Voltage Switching Applications

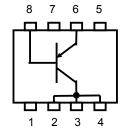
• High breakdown voltage: VCEO = -400 V

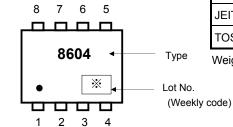
Absolute Maximum Ratings (Ta = 25°C)

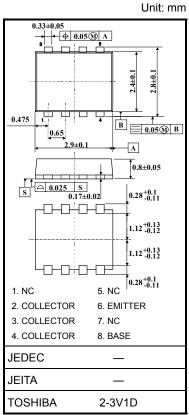
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-400	V	
Collector-emitter voltage		V _{CEO}	-400	V	
Emitter-base voltage		V _{EBO}	-7	٧	
Collector current	DC (Note 1)	Ic	-0.3	Α	
	Pulse(Note 1)	I _{CP}	-1		
Base current		Ι _Β	-0.25	Α	
Collector power dissipation	t=10s	P _C (Note 2)	-2.2	W	
	DC	FC (Note 2)	-1.1		
Junction temperature		Tj	-150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Figure 1. Circuit Configuration



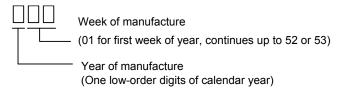






Weight: 0.05 g (typ.)

- Note 1 : Please use devices on condition that the junction temperature is below 150°C.
- Note 2: Mounted on FR4 board (glass epoxy, 1.6mm thick, Cu area: 645mm²)
- Note 3 : on lower left of the marking indicates Pin 1.
- Weekly code: (three digits)



Note 4: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

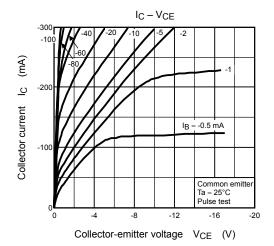
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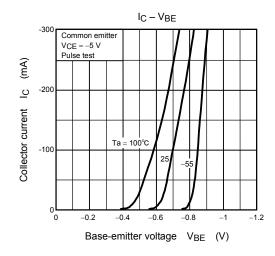


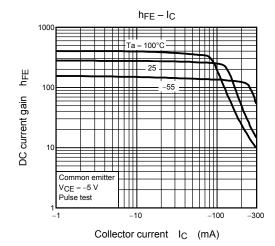
Electrical Characteristics (Ta = 25°C)

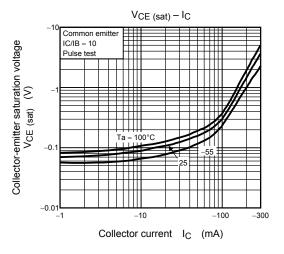
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I _{CBO}	$V_{CB} = -400 \text{ V}, I_{E} = 0$	_	_	-10	μΑ
Emitter cut-off cu	rrent	I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-1	μΑ
Collector-emitter	breakdown voltage	V (BR)CEO	I _C = -10 mA, I _B = 0	-400	_	_	V
DC current gain		h _{FE (1)}	$V_{CE} = -5 \text{ V}, I_{C} = -20 \text{ mA}$	140	_	450	
		h _{FE (2)}	$V_{CE} = -5 \text{ V}, I_{C} = -100 \text{ mA}$	140	_	400	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = -100 mA, I _B = -10 mA	_	-0.4	-1.0	V
Base-emitter volta	age	V _{BE (sat)}	I _C = -100 mA, I _B = -10 mA	_	-0.76	-0.9	V
Transition frequency		f _T	$V_{CE} = -5 \text{ V}, I_{C} = -50 \text{ mA}$	_	35	_	MH_Z
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	18	_	pF
-	Turn-on time	t _{on}	20 μs Input IB1 Output Input IB2 I	_	0.2	_	
	Storage time	t _{stg}		_	2.3		μs
	Fall time	t _f	$I_{B1} = -10 \text{ mA}, I_{B2} = 20 \text{ mA},$ Duty cycle $\leq 1\%$	_	0.2	_	

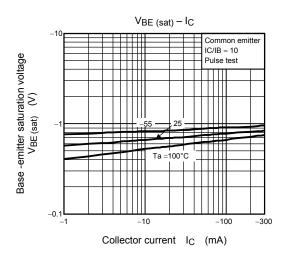
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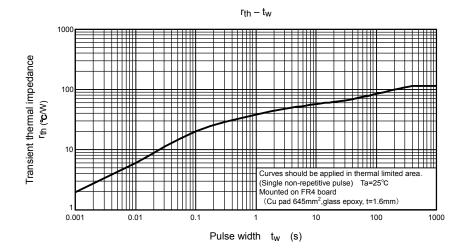


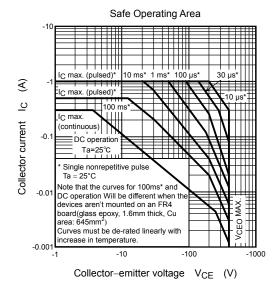






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